

# FVP18030IM3LSG1 Sustain

## Features

- Use of high speed 300V IGBTs with parallel FRDs
- Single-grounded power supply by means of built-in HVIC
- Sufficient current driving capability for IGBTs due to adding a buffer
- Isolation rating of 1500Vrms/min.
- Low leakage current due to using an insulated metal substrates

## Applications

- Sustain Part of a PDP(Plasma display panel)

## General Description

It is an advanced smart power module (SPM™) that Fairchild has newly developed and designed to provide very compact and optimized performance for the sustaining circuit of PDP driving system. It contains HVICs, buffers and low-loss high speed IGBTs that are needed to compose the sustaining circuits. Under voltage lock-out protection function enhances the system reliability. The high speed built-in HVIC provides optocoupler-less single power supply IGBT gate driving capability that further reduce the overall system size of PDP and the buffer provides high current driving capability of IGBTs.

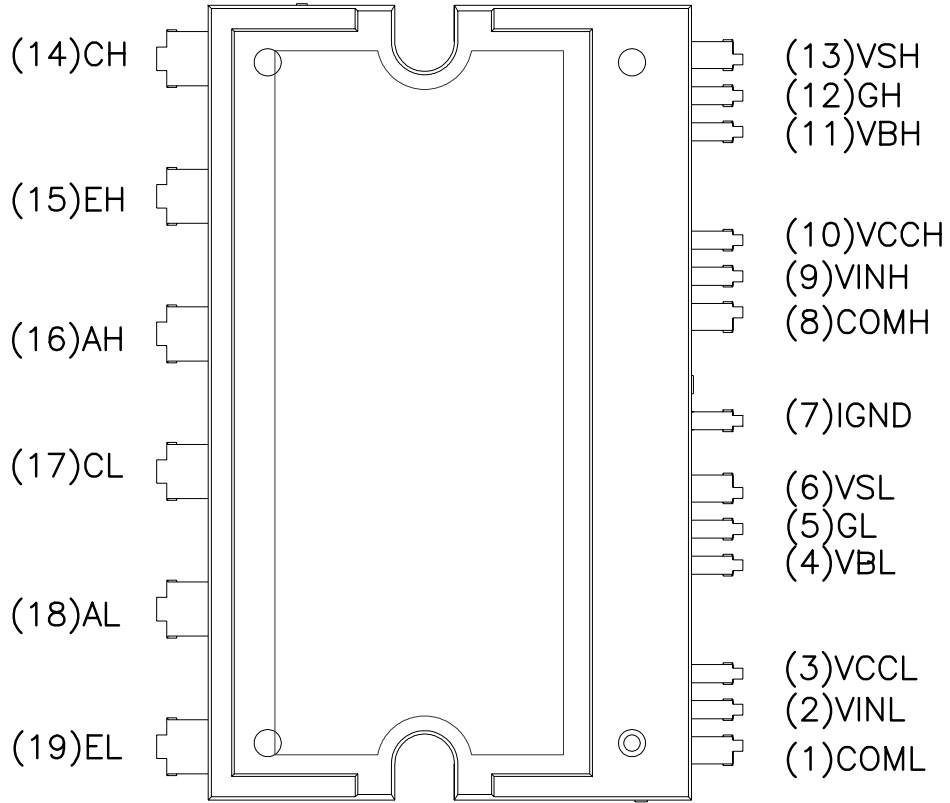
## Package Outlines



Figure 1.

**Pin Configurations**

**Top View**

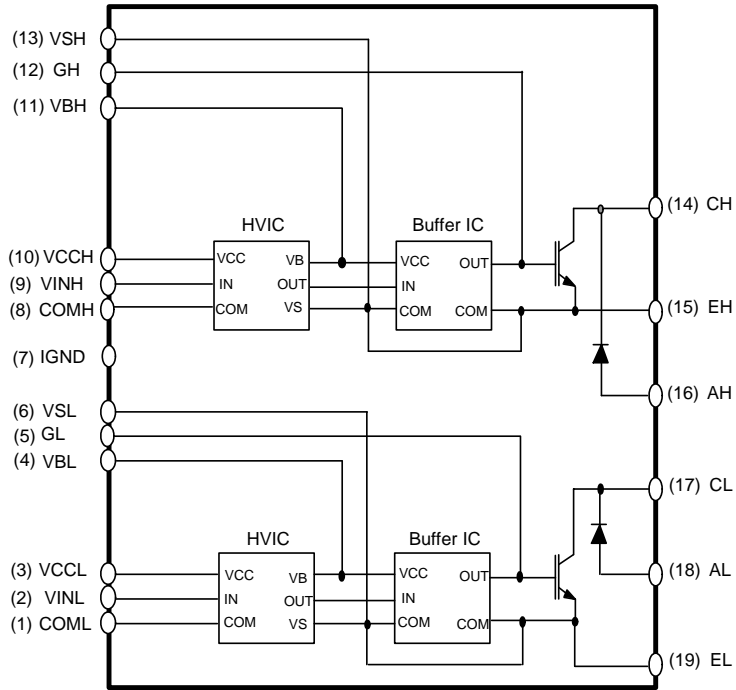


**Figure 2.**

## Pin Descriptions

Pin Number	Pin Name	Pin Descriptions
1	COML	Low-side Signal Ground
2	VINL	Low-side Signal Input
3	VCCL	Low-side Supply Voltage for HVIC
4	VBL	Low-side Floating Supply Voltage for Buffer IC and IGBT Driving
5	GL	Low-side Gate
6	VSL	Low-side Floating Ground for Buffer IC and IGBT Driving
7	IGND	IMS Ground
8	COMH	High-side Signal Ground
9	VINH	High-side Signal Input
10	VCCH	High-side Supply Voltage for HVICg
11	VBH	High-side Floating Supply Voltage for Buffer IC and IGBT Driving
12	GH	High-side Gate
13	VSH	High-side Floating Ground for Buffer IC and IGBT Driving
14	CH	High-side IGBT Collector
15	EH	High-side IGBT Emitter
16	AH	High-side Diode Anode
17	CL	Low-side IGBT Collector
18	AL	Low-side Diode Anode
19	EL	Low-side IGBT Emitter

**Internal Equivalent Circuit and Input/Output Pins (Bottom View)**



**Figure 3.**

**Absolute Maximum Ratings** ( $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified)

Symbol	Parameter	Conditions	Rating	Units
VCC	Control Supply Voltage	Applied between VCCL-COML, VCCH - COMH	20	V
VBS	Control Bias Voltage	Applied between VBL - VSL, VBH - VSH	20	V
VIN	Input Signal Voltage	Applied between VINL-COML, VINH - COMH	-0.3~17	V

Symbol	Parameter	Conditions	Rating	Units
VCE	Collector to Emitter Voltage	Between CL to EL, Between CH to EH $V_{GH-EH}=V_{GL-EL}=0V$ , $I_{CH}=I_{CL}=250\mu\text{A}$	300	V
VRRM	Peak Repetitive Reverse Voltage	Between CH to AH, Between CL to AL $I_{AH}=I_{AL}=250\mu\text{A}$	300	V
VIN	Input Signal Voltage	VINL, VINH	-0.3 to $V_{CC}+0.3$	V
$I_C$	Collector Current Continuous	Between CL to EL, Between CH to EH	180	A
$I_{F(AV)}$	Average Rectified Forward Current	Between CH to AH, Between CL to AL	10	A
$I_{CP}$	Pulsed Collector Current	Between CL to EL, Between CH to EH (Note1)	450	A
$I_{FP}$	Pulsed Diode Current	Between CH to AH, Between CL to AL (Note1)	100	A

**Notes :**1. Pulse Width = 100 $\mu\text{sec}$ , Duty = 0.1; half sine wave\* $I_{CP}$  limited by MAX  $T_J$ 

Symbol	Parameter	Conditions	Rating	Units
$P_d$	IGBT Dissipation	$T_C=25^\circ\text{C}$ per IGBT	167	W
		$T_C=100^\circ\text{C}$ per IGBT	67	W
	FRD Dissipation	$T_C=25^\circ\text{C}$ per diode	34	W
		$T_C=100^\circ\text{C}$ per diode	14	W
$T_J$	Operating Junction Temperature		-20 ~ 150	$^\circ\text{C}$
$T_C$	Module Case Operation Temperature		-20 ~ 125	$^\circ\text{C}$
$T_{STG}$	Storage Temperature		-40 ~ 125	$^\circ\text{C}$
$V_{ISO}$	Isolation Voltage	60Hz, Sinusoidal, AC 1 minute, Connection Pins to IMS substrate	1500	$V_{rms}$

**Thermal Resistance**

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	Junction to Case Thermal Resistance	Between CH to EH, Between CL to EL per IGBT	-	0.75	$^\circ\text{C/W}$
		Between CH to AH, Between CL to AL per Diode	-	3.70	$^\circ\text{C/W}$

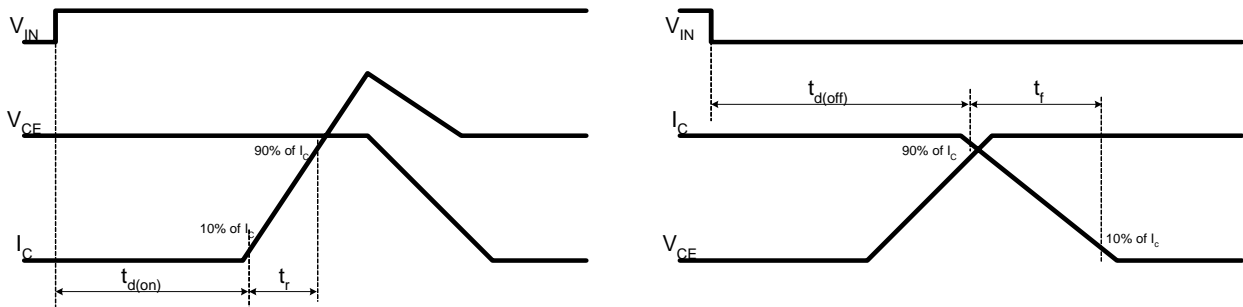
**Electrical Characteristics** ( $T_c = 25^\circ\text{C}$ , Unless Otherwise Specified)

Symbol	Parameter	Conditions		Min.	Typ.	Max.	Units
$I_{QCC}$	Quiescent VCC Supply Current	VCC = 15V VINL, VINH = 0V	VCCL-COML, VCCH-COMH	-	-	100	$\mu\text{A}$
$I_{QBS}$	Quiescent VBS Supply Current	VBS = 15V VINL, VINH = 0V	VBL- VSL, VBH- VSH	-	-	500	$\mu\text{A}$
$UV_{BSD}$	Supply Circuit Under Voltage Protection	Detection Level		10.1	11.3	12.5	V
$UV_{BSR}$		Reset Level		10.5	11.7	12.9	V
$V_{IN(ON)}$	ON Threshold Voltage	Applied between VINL-COML, VINH - COMH		3.0	-	-	V
$V_{IN(OFF)}$	OFF Threshold Voltage			-	-	0.8	V

Symbol	Parameter	Condition		Min.	Typ.	Max.	Units
$V_{CE(SAT)}$	IGBT Collector-Emitter Saturation Voltage	VCC = VBS = 15V VIN = 5V	$I_C = 40\text{A}, T_J = 25^\circ\text{C}$	-	-	1.4	V
			$I_C = 180\text{A}, T_J = 25^\circ\text{C}$	-	1.9	-	V
$V_F$	Diode Forward Voltage	VIN = 0V	$I_C = 10\text{A}, T_J = 25^\circ\text{C}$	-	-	1.4	V
$t_{dON}$	Switching Times	VCE=200V, VCC= VBS=15V $I_C = 20\text{A}$ VIN = 0V 5V, Inductive Load $T_c = 25^\circ\text{C}$ (Note2)		-	230	-	ns
$t_r$				-	54	-	ns
$t_{dOFF}$				-	260	-	ns
$t_f$				-	108	-	ns
$I_{CES}$	Collector-Emitter Leakage Current	VCE = 300V		-	-	250	$\mu\text{A}$
$I_R$	Diode Anode-Cathode Leakage Current	Between EH to CH Between EL to CL	$V_{\text{Anode-Cathode}}=300\text{V}$			250	$\mu\text{A}$

**Notes :**

2.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of internal drive IC. For the detailed information, please see Figure 4.



**Figure 4. Switching Time Definition**

## Typical Performance Characteristics

Figure 5. Typical Output Characteristics

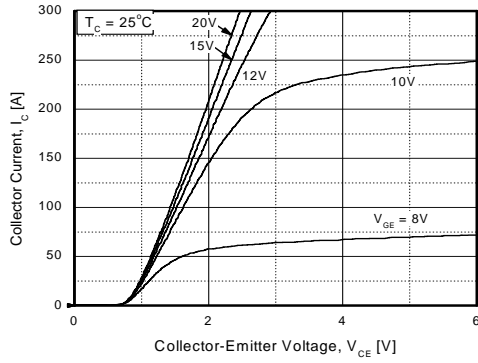


Figure 6. Typical Output Characteristics

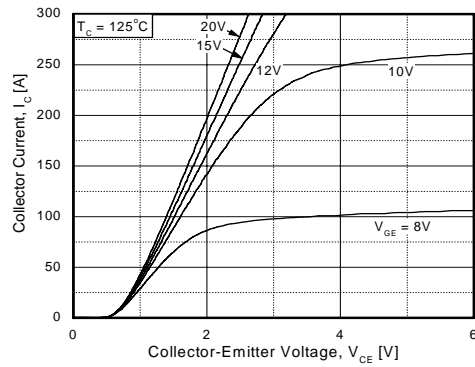


Figure 7. Typical Forward Voltage Drop

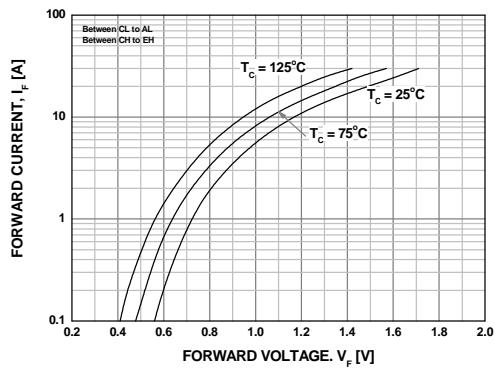
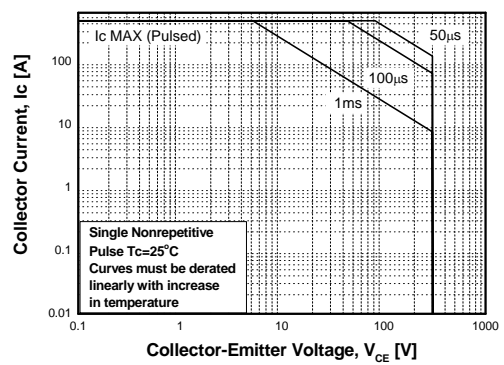
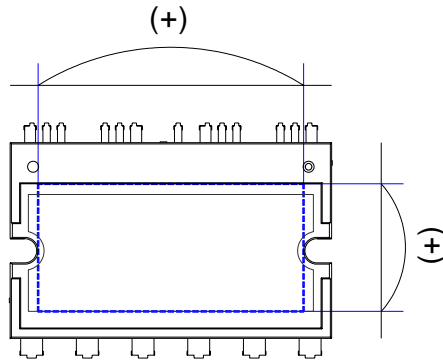


Figure 8. Typical Forward Voltage Drop



### Mechanical Characteristics and Ratings

Parameter	Conditions		Limits			Units
			Min.	Typ.	Max.	
Mounting Torque	Mounting Screw: - M3	Recommended 0.62N•m	0.51	0.62	0.72	N•m
Device Flatness		Note Figure 5	0	-	+100	μm
Weight			-	13.4	-	g



**Figure 9. Flatness Measurement Position**



### Detailed Package Outline Drawings

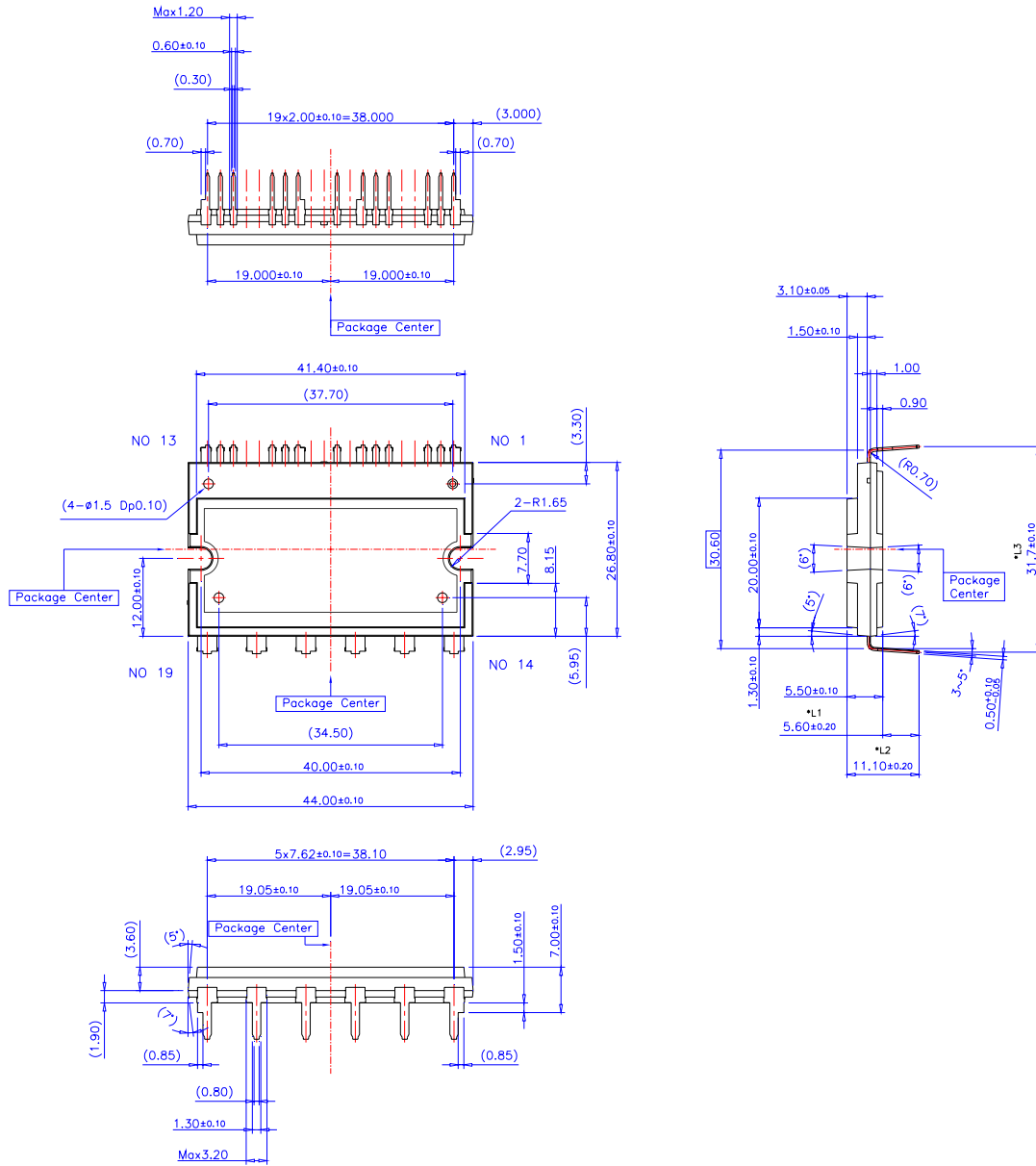



Figure 10.



**TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx <sup>®</sup>	GlobalOptoisolator <sup>™</sup>	Power247 <sup>®</sup>	SyncFET <sup>™</sup>
Across the board. Around the world. <sup>™</sup>	GTO <sup>™</sup>	PowerEdge <sup>™</sup>	TCM <sup>™</sup>
ActiveArray <sup>™</sup>	HiSeC <sup>™</sup>	PowerSaver <sup>™</sup>	The Power Franchise <sup>®</sup>
Bottomless <sup>™</sup>	<i>i-Lo</i> <sup>™</sup>	PowerTrench <sup>®</sup>	
Build it Now <sup>™</sup>	ImpliedDisconnect <sup>™</sup>	Programmable Active Droop <sup>™</sup>	TinyBoost <sup>™</sup>
CoolFET <sup>™</sup>	IntelliMAX <sup>™</sup>	QFET <sup>®</sup>	TinyBuck <sup>™</sup>
CROSSVOLT <sup>™</sup>	ISOPLANAR <sup>™</sup>	QS <sup>™</sup>	TinyLogic <sup>®</sup>
CTL <sup>™</sup>	MICROCOUPLER <sup>™</sup>	QT Optoelectronics <sup>™</sup>	TINYOPTO <sup>™</sup>
Current Transfer Logic <sup>™</sup>	MicroPak <sup>™</sup>	Quiet Series <sup>™</sup>	TinyPower <sup>™</sup>
DOME <sup>™</sup>	MICROWIRE <sup>™</sup>	RapidConfigure <sup>™</sup>	TinyWire <sup>™</sup>
E <sup>2</sup> CMOST <sup>™</sup>	MSX <sup>™</sup>	RapidConnect <sup>™</sup>	TruTranslation <sup>™</sup>
EcoSPARK <sup>®</sup>	MSXPro <sup>™</sup>	ScalarPump <sup>™</sup>	μSerDes <sup>™</sup>
EnSigna <sup>™</sup>	OCX <sup>™</sup>	SMART START <sup>™</sup>	UHC <sup>®</sup>
FACT Quiet Series <sup>™</sup>	OCXPro <sup>™</sup>	SPM <sup>®</sup>	UniFET <sup>™</sup>
FACT <sup>®</sup>	OPTOLOGIC <sup>®</sup>	STEALTH <sup>™</sup>	VCX <sup>™</sup>
FAST <sup>®</sup>	OPTOPLANAR <sup>®</sup>	SuperFET <sup>™</sup>	Wire <sup>™</sup>
FASTr <sup>™</sup>	PACMAN <sup>™</sup>	SuperSOT <sup>™</sup> -3	
FPS <sup>™</sup>	POP <sup>™</sup>	SuperSOT <sup>™</sup> -6	
FRFET <sup>®</sup>	Power220 <sup>®</sup>	SuperSOT <sup>™</sup> -8	

**DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

**LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

**PRODUCT STATUS DEFINITIONS**

**Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.